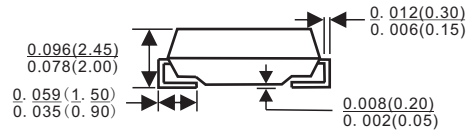
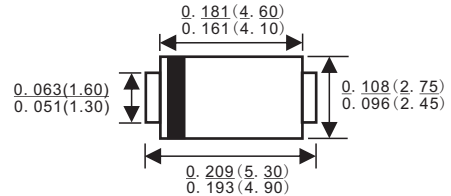




SMA/DO-214AC

Features

- ✧ For surface mounted application
- ✧ Easy pick and place
- ✧ Metal to silicon rectifier, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low VF
- ✧ High surge current capability
- ✧ Plastic material used carriers Underwriters Laboratory Classification 94V-0
- ✧ Epitaxial construction
- ✧ High temperature soldering: 260°C / 10 seconds at terminals



Mechanical Data

- ✧ Case: JEDEC SMA/DO-214AC Molded plastic
- ✧ Terminals: Pure tin plated, lead free
- ✧ Polarity: Indicated by cathode band
- ✧ Packaging: 12mm tape
- ✧ Weight: 0.064 gram

Dimensions in inches and(millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	SS 12	SS 13	SS 14	SS 15	SS 16	SS 19	SS 110	SS 115	SS 120	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	20	30	40	50	60	90	100	150	200	V
Maximum RMS Voltage	V_{RMS}	14	21	28	35	42	63	70	105	150	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	60	90	100	150	200	V
Maximum Average Forward Rectified Current at T_L (See Fig. 1)	$I_{(AV)}$	1.0									A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30									A
Maximum Instantaneous Forward Voltage (Note 1) IF= 1.0A @ 25°C @ 100°C	V_F	0.5		0.75		0.80		0.90		V	
Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=125^\circ\text{C}$	I_R	0.4			0.1					mA	
		10		5.0		2.0				mA	
Maximum DC Reverse Current at $V_R=33V$ & $T_A=50^\circ\text{C}$	HT_{IR}	-			5.0						uA
Typical Junction Capacitance (Note 3)	C_j	50									pF
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	28									°C/W
	$R_{\theta JA}$	88									
Operating Temperature Range	T_J	-65 to +125			-65 to +150						°C
Storage Temperature Range	T_{STG}	-65 to +150									°C

- Notes:
1. Pulse Test with PW=300 usec, 1% Duty Cycle
 2. Measured on P.C.Board with 0.2" x 0.2" (5.0mm x 5.0mm) Copper Pad Areas.
 3. Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (SS12 THRU SS120)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

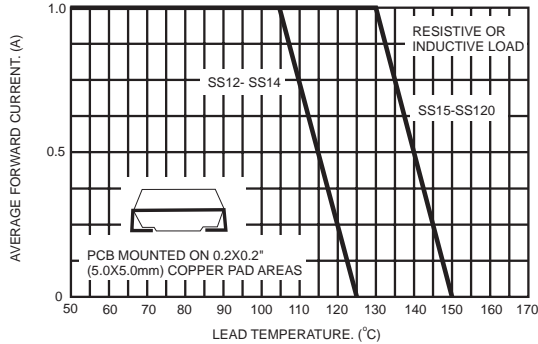


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

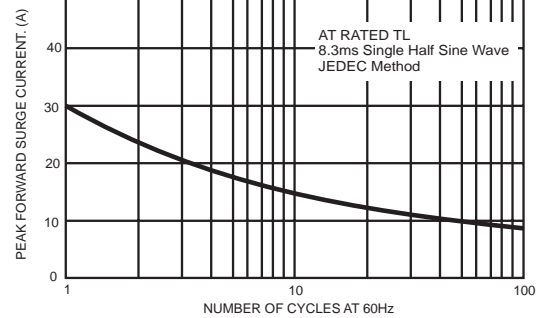


FIG.3- TYPICAL FORWARD CHARACTERISTICS

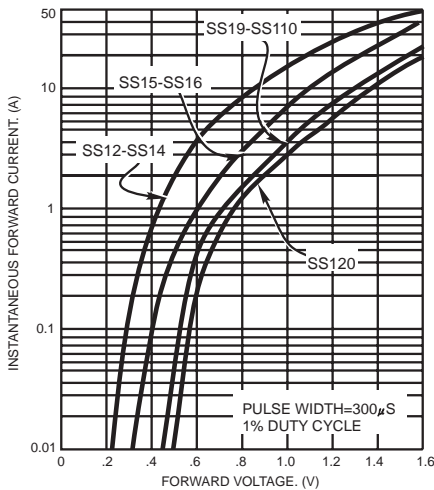


FIG.4- TYPICAL REVERSE CHARACTERISTICS

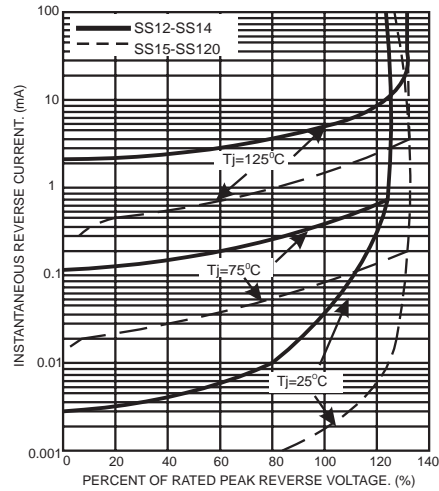


FIG.5- TYPICAL JUNCTION CAPACITANCE

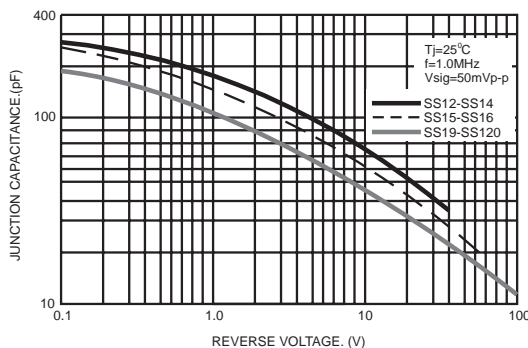
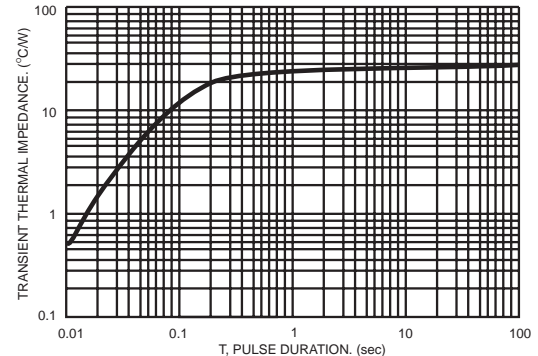


FIG.6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS



PACKAGE	SPQ/PCS	CARTON SPQ/PCS	CARTON SIZE/CM	CARTON GW/KG	CARTON NW/KG
SMA	5000/REEL	80000	36X30.6X31	12.00	11.00

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